## Fluorescence and phosphorescence from individual C 60 m olecules excited by local electron tunneling

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U sing the highly localized current of electrons tunneling through a double barrier Scanning Tunneling M icroscope (STM) junction, we excite luminescence from a selected C  $_{60}$  molecule in the surface layer of fullerene nanocrystals grown on an ultrathin N aC  $_{1}$  lm on A u (111). In the observed luminescence uorescence and phosphorescence spectra, pure electronic as well as vibronically induced transitions of an individual C  $_{60}$  molecule are identified, leading to unambiguous chemical recognition on the single-molecular scale.

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Light em ission induced by electrons tunneling through the junction formed by the sample and the tip of a Scanning Tunneling M icroscope (STM) has been proposed to characterize the optical properties of nanoscale objects at surfaces [1]. Contrary to conventional non-local techniques, the local character of this method over the unique possibility to select and probe individual atoms, molecules or clusters on surfaces.

Photon emission due to the decay of localized surface plasmons, excited by inelastic electron tunneling (IET) has been observed on metal surfaces [2, 3], as well as on supported metallic nanoparticles [4]. Luminescence spectra have been acquired from semiconductor heterostructures [5], quantum well states of metallic lms [6]. Recently, luminescence from supported molecules has been obtained [7, 8] by successfully decoupling them from the metallic substrate in order to avoid quenching of the radiative transitions [9, 10], using either a thin oxide lm [7] or severalmolecular layers [8].

However, unambiguous chemical identication of single complex molecules requires the observation and identication of several vibrational and/or electronicvibrational transitions, which are the spectroscopic ngerprint of the species. Here we present the rst observation of energy resolved lum in escence from an individually selected C 60 m olecule excited by electrons tunneling through a double barrier STM junction. A comparison with the lum inescence spectra obtained by non-local laser spectroscopy from dispersed C<sub>60</sub> molecules in rare gas and glass matrices [11, 12, 13, 14, 15, 16], and from solid C<sub>60</sub> [17, 18, 19] enables us to demonstrate the molecular origin of the detected light and to identify the observed spectral features with pure electronic transitions and with vibronic transitions induced via Jahn-Teller (JT) and Herzberg-Teller (HT) coupling [20, 21]. The present novel observation of both, uorescence (singletto-singlet transitions) and phosphorescence (triplet-tosinglet transitions) constitutes a solid basis for the chemical identication of an individual C  $_{60}$  m olecule.

C 60 nanocrystals were grown on NaC l layers deposited onto a Au (111) substrate. NaClwas evaporated from a K nudsen cellon a clean Au (111) surface at room temperature. Subsequently, the C  $_{60}$  m olecules were sublim ated on the NaCl covered substrate. The experiments were performed with a homebuilt ultrahigh vacuum (UHV) STM operating at a tem perature of 50 K, using cut PtIr tips. The photons em itted from the tunnel junction were collected by a lens placed inside the cryostat, guided through an optical system outside the UHV chamber to the spectrograph, and detected by a CCD camera. The wavelength resolution of the experim ent was 8 nm, corresponding to 20 meV in the energy range of interest. The spectra were acquired with closed feedback loop while tunneling over a de ned position on the sample, e.g. over a single molecule, with a typical acquisition time of 300 s. Bias voltages V refer to the sample voltage with respect to the tip.

NaCl forms (100)-term inated islands on Au (111) of thickness between 1 and 3 m onolayers and width up to 1 m. Contrary to the layer-by-layer growth of C  $_{60}$  on Au (111) leading to extended islands found by STM [22], on NaClelectron microscopy studies [23] revealed that the C 60 m olecules aggregate into hexagonal or truncated triangular nanocrystals with a height of several molecular layers. This situation is well illustrated in Fig. 1, where  $C_{60}$  islands grown on both, the bare Au (111) (A) and the NaCl covered surface (B-D) are visible. The nanocrystals present a minimum height of two layers of  $C_{60}$  m olecules (island B). The nucleation of the  $C_{60}$ nanocrystals starts at defects of the NaCllayer (protrusions or vacancies), m onatom ic steps of A u (111) (covered with NaCl), or edges of the second layer of NaCl. As shown in Fig. 1 (b), the C 60 m olecules form hexagonally arranged layers with an intermolecular distance of 1 nm.

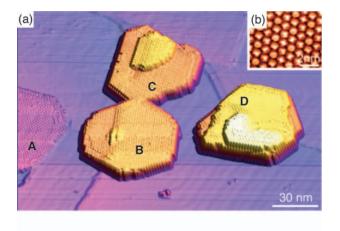


FIG. 1: (color online). (a) STM image of C  $_{60}$  nanocrystals form ed on a NaC lultrathin lm grown on Au (111) (V=3V, I =  $0.02\,\mathrm{nA}$ ). Island A is a C  $_{60}$  monolayer on Au (111), the small blue triangle below A is part of the bare Au surface. Hexagonal island B, and truncated triangular islands C and D consist of up to two, three, and four C  $_{60}$  molecular layers, respectively, on NaCl. (b) Sub-molecular resolution on island B (V=3V, I= $0.1\,\mathrm{nA}$ ).

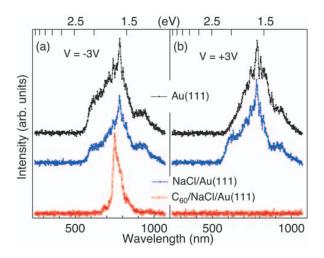


FIG. 2: (color online). STM -induced photon em ission spectra acquired with (a) negative ( $V = 3 \ V$ , I = 1 nA) and (b) positive ( $V = + 3 \ V$ , I = 1 nA) bias polarity. Spectra acquired on bare Au (111) and on NaCl thin Im reveal characteristic em ission from a localized surface plasm on. Em ission from C  $_{60}$  can only be excited at negative voltages. Spectra are vertically shifted for clarity.

Figure 2 shows STM—induced optical spectra from the bare Au (111) surface, the NaC lcovered Au (111) surface and from a C  $_{60}$  nanocrystal. Photons em itted from Au (111) originate from an ET process, involving excitation and decay of a surface plasm on localized between the tip and the surface [2, 3, 24]. A similar spectral shape is observed over the NaCl layer, however with reduced intensity due to the dielectric NaCl spacer layer. Char-

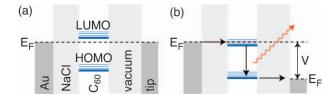


FIG. 3: (color online). Energy diagram of the double barrier tunneling junction at (a) at zero-bias voltage, (b) applied negative voltage, corresponding to the conditions for lum inescence.

acteristic for this process is the energy-dependent quantum cut-o [2] (not shown) and the possibility to excite the em ission with both bias polarities [3], as shown in Fig. 2. The third spectrum in Fig. 2(a) was acquired over a single C  $_{60}$  m olecule in the surface of a nanocrystal (V=3V, I=1nA). Light em ission from C  $_{60}$  is observed only for bias higher than the threshold voltage of V=2.3V. The em ission onset is located at 680nm and its position is independent of the voltage. For positive voltages up to +4.5 V no photon em ission is detected. These observations clearly distinguish the light em ission spectrum of C  $_{60}$  from those acquired over the substrate

(Au and NaCl).

The occurrence of lum in escence from the C  $_{60}$  m olecule is related to the characteristics of the tunneling junction, as shown in Fig. 3. At negative bias voltage larger than 2.3 V, the highest-occupied molecular orbital (HOMO), which is completely led for C 60 in the ground state, is higher than the Ferm i level ( $E_F$ ) of the tip. The electrons are extracted from the HOMO and tunnel to the tip, while the lowest-unoccupied molecular orbital (LUMO), now lower than the Ferm i level of the sample, is populated by the electrons tunneling from the substrate, electrons that can radiatively decay into the partially empty HOMO (hot electron/hole in jection). The fact that lum in escence is not observed for tunneling from the tip to the sample for voltages up to +4.5 V m ay be due to the asym m etry of the HOMO-LUMO gap with respect to  $E_{\rm F}$ [25] and to the di erent properties of the two tunneling barriers (vacuum and NaCl) [26].

Figure 4(a) shows the same lum inescence spectrum obtained from an individual  $C_{60}$  m olecule as in Fig. 2(a), but corrected for the quantum e-ciency of the detection system. In order to identify the electronic and vibronic transitions giving rise to the observed emission, we compare our results with laser-induced high-resolution photolum inescence data [13, 14] and with quantum them ical calculations [14, 21]. It is now established that the lowest excited singlet state  $S_1$  has mixed  $T_{1g}$ ,  $T_{2g}$  and  $G_g$  tharacter [14]. The electric dipole transitions from this state to the ground state  $S_0$  ( $A_g$ ) are symmetry forbidden, but they occur through HT and JT electron-vibration coupling mechanisms of intensity borrowing [20, 21]. The relaxation of the selection rules due to symmetry lower-

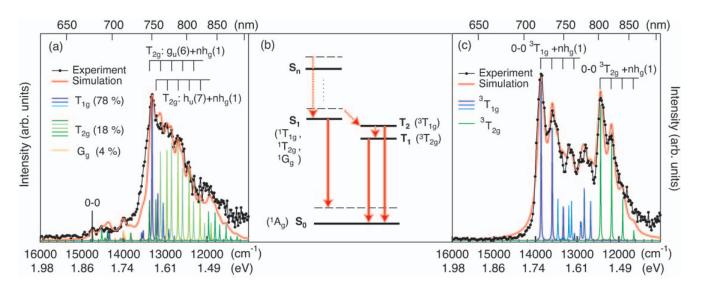


FIG. 4: (color online) (a) STM -induced light em ission spectrum assigned to  $C_{60}$  uorescence (V=3V, I=1nA) and calculated spectrum. (b) Schematic diagram of the lowest singlet ( $S_{1}$ ) and triplet ( $T_{1}$ ) states. Horizontal solid lines: pure electronic levels; horizontal dashed lines: vibrational levels. Solid arrows represent electronic transitions; dashed arrows represent radiationless mechanisms of relaxation (internal conversion, intersystem crossing, vibrational relaxation). (c) STM -induced light em ission spectrum assigned to  $C_{60}$  phosphorescence (V=3V, I=1nA) and calculated spectrum. For both simulations, experimentally determined frequencies for the vibronically induced  $S_{0}$   $S_{1}$  ( $T_{1g}$ ,  $T_{2g}$ ,  $G_{g}$ ) and  $S_{0}$   $T_{1}$  ( $^{3}T_{2g}$ ),  $T_{2}$  ( $^{3}T_{1g}$ ) transitions are used, see Tab. I [14, 27]. Each component has a Lorentzian lineshape, broadened by 150 cm  $^{1}$  (a) and 200 cm (c) to obtain the calculated spectra (red).

TABLE I: HT and JT active modes used in the simulation of the STM-induced light emission spectra shown in Fig. 4(a,c). For the most intense modes contributing to the spectra, the experimental frequencies [14, 27] are indicated in brackets.

Fluorescence: S <sub>0</sub> S <sub>1</sub>		Phosphorescence: S <sub>0</sub> T <sub>1</sub> ;T <sub>2</sub>
S <sub>1</sub> (T <sub>1g</sub> )	HT: $t_{1u}$ (4) (1430 cm $^{1}$ ), $h_{u}$ (7) (1566 cm $^{1}$ ), $h_{u}$ (1), $h_{u}$ (3), $h_{u}$ (3), $h_{u}$ (5). JT: $h_{g}$ (7),	$T_1$ ( $^3T_{2g}$ ) $JT:h_g$ (1) (266 cm $^1$ ).
S <sub>1</sub> (T <sub>2g</sub> )	$a_{g}$ (2), $h_{g}$ (1). HT: $g_{u}$ (6) (1410 cm $^{1}$ ), $h_{u}$ (7) (1566 cm $^{1}$ ), $g_{u}$ (1), $h_{u}$ (1), $g_{u}$ (4), $h_{u}$ (5). JT: $h_{g}$ (1) (266 cm $^{1}$ ),	$T_2$ ( $^3T_{1g}$ ) HT: $t_{2u}$ (3) (1037 cm $^1$ ), $h_u$ (1), $h_u$ (2), $h_u$ (4), $a_u$ (1), $g_u$ (4), $t_{1u}$ (3). JT: $h_g$ (1) (266 cm $^1$ ).
S <sub>1</sub> (G <sub>g</sub> )	$h_g$ (7), $a_g$ (2). HT: $h_u$ (4) (738 cm $^1$ ), $h_u$ (2), $h_u$ (3), $g_u$ (3), $g_u$ (5), $t_{2u}$ (2).	

ing in the C 60 lattice gives rise to a very weak lum inescence signal corresponding to the pure electronic (0-0) S<sub>1</sub> transition, found at 678 nm, as indicated in Fig. 4(a). The red shift of about 40 nm with respect to C<sub>60</sub> in the gas phase is attributed to environmental e ects [13, 14, 16]. The observation of the pure electronic origin helps to determ ine the vibronically induced false origins as in the high-resolution photolum inescence m easurem ents [11, 14]. The uorescence spectra are sim ulated using calculated oscillator strengths and experim entally determ ined frequencies for the HT vibronically induced S<sub>0</sub>  $S_1$  ( $T_{1q}$ ,  $T_{2q}$ ,  $G_q$ ) transitions, and the experim ental frequencies for the JT active modes, as presented in Fig. 4 (a) and in Tab. I [14, 27]. The contribution of each sym m etry character of  $S_1$  varies slightly from one probed molecule to another, re ecting the known

sensitivity of C  $_{60}$  to the local environm ent [14, 18, 28]. The agreem ent between measured and calculated spectra in Fig. 4(a) demonstrates the local character of the measurem ent and provides evidence for the preservation of the C  $_{60}$  molecular properties in the van de W aals crystal, characterized by weak interactions between the molecules.

Interestingly, we also observe another type of electronic transitions, shown in Fig. 4 (c). Similar spectra have been reported for laser-induced luminescence from solid C  $_{60}$  [17, 18, 19], and have recently been identified as phosphorescence originating from triplet to singlet ground state transitions [28]. Although symmetry and spin-forbidden, intense pure electronic (0-0) triplet to singlet transitions have been observed in C  $_{60}$  phosphorescence spectra [12, 15]. The low-energy part of the spectrum

in Fig. 4(c) arises from the  $S_0$   $T_1$  ( $^3T_{2g}$ ) transition, characterized by the intense 0-0 origin at 803 nm and by the progression of a JT active mode, see Tab. I, in agreement with phosphorescence spectra obtained from dispersed  $C_{60}$  molecules [11, 12, 15]. The electronic origin is shifted by 27 nm to the red with respect to the estimated gas phase energy [12, 28]. The high-energy region of the spectrum presents a similar shape, i.e. an intense transition, located at 720 nm, and a progression of vibronic bands. The observed energy di erence of

0.18 eV between the two most intense features in the spectrum shown in Fig. 4(c) is in agreement with electron energy loss spectroscopy results [28, 29] and with calculations [30] for the splitting of the lowest C  $_{60}$  triplet states. Therefore, the high-energy part of the spectrum in Fig. 4 (c) is assigned to transitions from the next higher  $T_2$  ( ${}^3T_{1q}$ ) [28]. The good agreem ent triplet state S<sub>0</sub> between the calculated and the measured spectra allows us to assign the STM -induced phosphorescence spectrum to light emission from an individual C 60 molecule, as in the case of uorescence. This nding contradicts previous interpretations of similar spectra obtained by laser induced lum inescence from solid C 60 in term sofexcitonic em ission [17] or em ission delocalized over more than one C<sub>60</sub> m olecule [18, 19].

The observation of both radiative relaxation processes, uorescence and phosphorescence, in the STM induced light emission may be related to (i) the sensitivity of the probed C 60 m olecule to the local environm ent in the nanocrystal and/or to (ii) the actual tunneling conditions. (i) Dierences in the local C  $_{60}$ environment may induce a modication of the mixed character of the states and/or a relaxation of the selection rules, as observed in ensemble-averaged experim ents [11, 12, 13, 14, 15, 16, 17, 18, 19, 28]. Novel, here, is the fact that the in uence of the environm ent is probed on an individual selected molecule. (ii) Even for equal nom inal tunneling param eters, the actual tunneling conditions can vary from one measurement to the other. Tip shape and composition, current instabilities, or electric eld uctuation may in uence the relaxation paths, for example by enhancing the intersystem crossing, and increasing the population of the triplet states. The identication of the physical origin of the observation of both, uorescence and phosphorescence calls for future tim eresolved lum inescence studies em ploying both, non-local laser excitation and local STM -induced excitation of supported molecules.

To sum m arize, unam biguous chem ical identi cation of individual C  $_{60}$  m olecules is obtained via their lum inescence induced by tunneling electrons. Em ission from three electronic states m apping m ore than twenty vibrational Jahn-Teller and H erzberg-Teller m odes of the m olecule is identi ed, in excellent agreement with the

known energies of the electronic [11, 12, 13, 14, 15, 28] and vibrational [14, 21, 27] levels of  $C_{60}$ . The present observation of local uorescence and phosphorescence demonstrates the capability of STM -induced light em ission for the chemical recognition on the single-molecular scale.

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